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Nonlocal transport in the charge density waves of o -TaS₃

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We studied the nonlocal transport of a quasi-one-dimensional conductor o -TaS₃. Electric transport phenomena in charge density waves include the thermally excited quasiparticles and collective motion of charge density waves (CDWs). In spite of its long-range correlation, the collective motion of a CDW does not extend far beyond the electrodes, where phase slippage breaks the correlation. We found that nonlocal voltages appeared in the CDW of o -TaS₃, both below and above the threshold field for CDW sliding. The temperature dependence of the nonlocal voltage suggests that the observed nonlocal voltage originates from the CDW even below the threshold field. Moreover, our observation of nonlocal voltages in both the pinned and sliding states reveals the existence of a carrier with long-range correlation, in addition to sliding CDWs and thermally excited quasiparticles.

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Nonlocal properties in charge density waves (CDWs) have been attracting interest for decades.^{1–3} Since electric transport phenomena include collective motion,⁴ it is natural to expect a sliding CDW to be a possible source of nonlocal transport.¹ The correlation of the CDW phase has been estimated in the 1–100 μm range,^{1,5–13} which is long enough to allow experimental studies. The correlation inside the sliding region has been confirmed. However, it has been shown that the correlation of a sliding CDW does not extend far beyond the electrodes, where phase slippage may destroy the correlation.^{2,3}

In this Brief Report, we report a nonlocal transport phenomenon with a quasi-one-dimensional conductor o -TaS₃. Following the pioneering work by Gill,¹ we compared current-voltage characteristics obtained with normal and transposed electrode configurations, as well as with nonlocal detection (Fig. 1). We found that nonlocal voltages appeared in the CDW of o -TaS₃, both below and above the threshold field for CDW sliding. The sign of the observed nonlocal voltage was opposite to that of the spreading resistance.^{14,15} In addition to this, the temperature dependence of the nonlocal voltage suggests that the observed nonlocal voltage originates from the CDW. Moreover, our observation of nonlocal voltages in both the pinned and sliding states reveals the existence of a carrier with long-range correlation, in addition to sliding CDWs and thermally excited quasiparticles. Finally, we compared our observation to the coexistence of two CDWs in o -TaS₃ (Refs. 16 and 17) and found it is closely related to topological dislocations in CDWs.

We performed a four-probe measurement, which requires a voltmeter with a high input impedance so that the leakage current to the voltmeter becomes negligible. For fully gapped CDW materials, such as o -TaS₃, the use of four-probe measurement is usually difficult especially at low temperatures where the sample resistance often exceeds the typical input impedance of a voltmeter, for example, $Z_{in} \sim 1 \text{ G}\Omega$. We exploited an electrometer (Keithley 6512, $Z_{in} > 200 \text{ T}\Omega$) to measure the voltage drop of the o -TaS₃ samples.

o -TaS₃ crystals were synthesized with a standard chemical vapor transport method. A pure tantalum sheet and sulfur

powder were put in a quartz tube. The quartz tube was evacuated to 1×10^{-6} Torr and heated in a furnace at 530 $^{\circ}\text{C}$ for two weeks. The electrodes were made using 50- μm diameter silver wires glued with silver paint. Gold thin film was deposited on the crystal before the silver wires were attached to reduce the contact resistance to 1 Ω at room temperature. The spacing between the electrodes was typically 200 μm and the sample cross section was $50 \times 5 \mu\text{m}^2$ (width \times thickness).

Figure 2 shows the temperature dependence of the resistance of a o -TaS₃ crystal. The result shows the well-known features of o -TaS₃, a Peierls transition temperature of 220 K, an Arrhenius-type temperature dependence with an activation energy of 790 K, and a deviation from the Arrhenius plot below 100 K. We checked the contact resistance by comparing the four- and two-terminal resistances and found it was negligible in the room temperature to 40 K range. We also confirmed that the result was unaffected by the difference between substrates by comparing data obtained with the silica and sapphire substrates. Based on these considerations, we confirmed that the four-terminal measurement was prop-

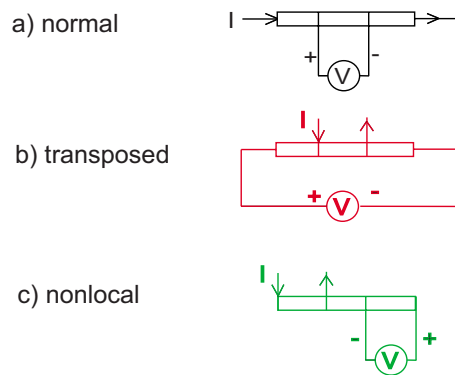


FIG. 1. (Color online) Configurations for the measurements: (a) normal configuration, (b) transposed configuration, and (c) nonlocal configuration. The polarity of the voltmeter in the nonlocal configuration provides a positive value when the spreading resistance is dominant.

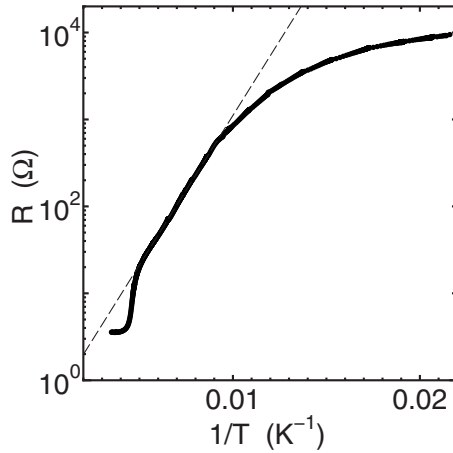


FIG. 2. Temperature dependence of sample resistance. Broken line is an Arrhenius fit $R \propto \exp(T/T_0)$, with $T_0 = 790$ K.

erly performed over the entire temperature range of the measurement.

Figure 3 shows the current-voltage (I - V) characteristics at 130 K in the normal and transport configurations, as well as the nonlocal voltage. The I - V characteristics with the normal configuration (black line) and with the transposed configuration (red line) coincide in a low current regime where Ohmic behavior is observed. Above the threshold of nonlinear conduction, we detected a discrepancy between the two configurations. This discrepancy can be understood as the phase-slip voltage accompanied by CDW sliding.^{1,2} When the CDW slides under a condition where the regions outside the current electrodes are strongly pinned, elastic deformation is induced in the CDW. In the vicinity of each electrode, the elastic deformation relaxes by breaking CDW phase continuity. In the transposed configuration [Fig. 1(b)], the measured voltage is affected by the phase slip, in contrast to the normal configuration [Fig. 1(a)], hence the difference between these two configurations as shown in Fig. 3 reveals that the phase slip really occurred in the sample.

We also observed nonlocal voltage as shown in Fig. 3 (green line) by using the nonlocal configuration [Fig. 1(c)]. The result shows that at 130 K, a negative voltage was detected at a pair of electrodes 200 μm away. The magnitude

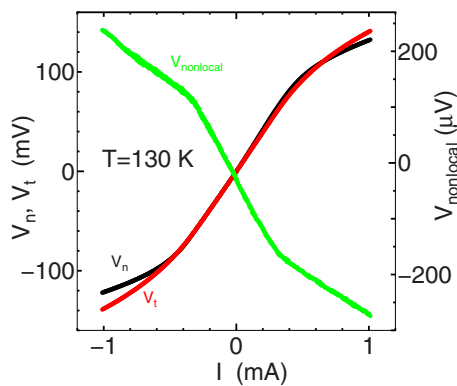


FIG. 3. (Color online) Current-voltage characteristics at 130 K for the normal, transposed, and nonlocal configurations, denoted by black, red (gray), and green (light gray) curves, respectively.

of the nonlocal voltage was around 200 μV at 1 mA. This voltage was large enough to be measured with our ultrahigh impedance voltmeter, whose minimum detectable voltage was 10 μV . The voltage was proportional to the injected current, with kinks at ± 0.3 mA, above which the slope of the I - V curve became moderate. The emergence of a voltage at the nonlocal probes is fascinating since Gill reported that there was no detectable signal in the CDW state of NbSe_3 .¹ Such an attempt has also been made for other CDW systems, however, the nonlocal effects were unlikely to extend over the electrode, except via strain distribution.³

We first compared our observation to a trivial source, known as spreading resistance, which could affect the nonlocal voltage probes.^{14,15} When the current is injected from a tiny electrode into a bulk sample, it cannot flow homogeneously until it spreads over a cross section. In the vicinity of the electrodes, the flow lines are curved and some of them travel in the opposite direction to the counterelectrode. At the sample surface, the electric potential $U(x)$ of position x is expressed by

$$U(x) = -E \frac{t'}{\pi} \operatorname{arccosh} \left| \frac{\cosh(\pi l/t') - \exp(\pi x/t')}{\sinh(\pi l/2t')} \right|, \quad (1)$$

where E denotes an applied field, l is the electrode length, and $t' = t\sqrt{A}$ is a reduced thickness with A being the anisotropic ratio of conductivity.^{14,15} In addition, the effective cross section for the current is limited to the specific distance $\sim t'$ and an additional contribution to resistance emerges, known as spreading resistance. An important feature of spreading resistance is that it obeys Ohm's law since its nature is the restriction of the current path. In our configuration for nonlocal detection [Fig. 1(c)], the contribution of the spreading resistance must generate a *positive* voltage between the voltage probes.

In fact, the observed nonlocal voltages were *negative* as shown in Fig. 3. Moreover, the temperature dependence of the nonlocal voltage suggests that CDW is closely related to its origin. Figure 4(a) shows the temperature evolution of the nonlocal voltages at 130, 180, and 250 K. At 180 K, although the kink and nonlinearity became less pronounced, the nonlocal voltage was negative. In contrast, at 250 K, above the Peierls transition ($T_p = 220$ K), the polarity was reversed and became positive. The slope of the I - V curve was $2.1 \times 10^{-2} \Omega$. This is in good agreement with the estimation of spreading resistance $2.8 \times 10^{-2} \Omega$ estimated using Eq. (1) with an anisotropy ratio of $A = 500$.¹⁵ To confirm that this is not an artifact from the measurement circuit, we performed several sets of experiments, including a comparison of the data while inverting the polarity of the electrodes of both the current generator and the voltmeter. We also checked the reproducibility by using different specimens and cryostats. All the data were consistent and we concluded that the observed *negative* nonlocal voltage was really a property of the samples. Hence it is unlikely that the nonlocal voltage can be attributed to the trivial spreading resistance, whereas its attribution to CDW is plausible.

In addition, the voltages were nonlinear functions of the current with apparent kinks (Fig. 3). The positions of the

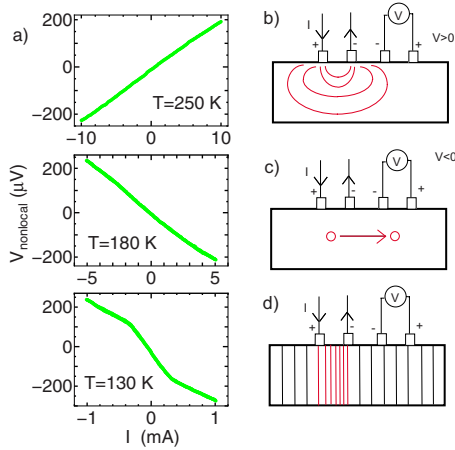


FIG. 4. (Color online) (a) Temperature evolution of the nonlocal voltages at 130, 180, and 250 K. Polarity inversion was seen below and above the Peierls transition, 220 K. (b) Schematic diagram of flow lines to provide spreading resistance. (c) Possible correlation between current and voltage probes via dislocation lattice. (d) Correlation of sliding CDW is Fig. 1 exceeded over current probes.

kinks in the nonlocal voltage were found to be close to the threshold of nonlinear conduction of the CDW. When the sample was in a CDW state, the Peierls gap opens at Fermi surfaces, so that thermally activated quasiparticles and collective motion of the CDW contribute to electric conduction. The former provides Ohmic currents and, as discussed above, might contribute to positive nonlocal voltages. Hence, a quasiparticle is also ruled out as a major contributor to the nonlocal voltage and the collective motion becomes a candidate for the nonlocal voltage. Nevertheless, the observed kinks are clearly related to the onset of CDW sliding.

For the sliding CDW to provide the nonlocal voltage, probed $200\ \mu\text{m}$ away from the emitting electrodes, the phase correlation length of the CDW should be at least comparable to or longer than the traveling length. There are several estimations for the phase correlation length ranging from 1 to $100\ \mu\text{m}$.¹⁻¹³ X-ray diffraction typically provides the lengths of the order of $1\ \mu\text{m}$,^{9,11,12} whereas other kinds of estimations based on CDW dynamics provide longer values of up to $100\ \mu\text{m}$.^{1,6,7,13} Moreover, the phase coherence length is a strong function of defect concentration and will differ for different materials and even for samples of the same material. Consequently, a consideration of the correlation length does not deny the possibility of a sliding CDW being the origin of the nonlocal voltage.

However, even if the CDW correlation could extend such a distance, the standard interpretation of the phase-slip voltage suggests that the phase correlation might be lost in the vicinity of the electrode.^{1,2} As shown in Fig. 3, the difference between the voltages of the normal and transposed configurations implies that the CDW is in the sliding state with a considerable rate of phase slip.² Moreover, it should be noted that the nonlocal voltage was observed even below the kinks. Hence, the source of the nonlocal voltage must be present whether or not the CDW slides.

Now we may propose a possible model based on the above discussions. Since the CDW phase correlation is de-

stroyed in the vicinity of the electrodes and the nonlocal voltage is also seen below the kinks, we must seek for a different transport mechanism originated from the CDW state, rather than sliding. Its properties should include Ohmic behavior and it should possess a spatial correlation over at least $200\ \mu\text{m}$. A recent synchrotron diffraction study reports that two kinds of CDWs, incommensurate and commensurate CDWs, coexist in $o\text{-TaS}_3$ (Ref. 16) and a subsequent ultrafast optical pump-probe study of $o\text{-TaS}_3$ also provides evidence for two types of CDW phases.¹⁷ Discommensuration or a lattice of topological dislocations¹⁸ exists from the Peierls temperature to around 50 K.¹⁶ Each topological dislocation is accompanied by a charge, which can move along the chain direction of a CDW. The distance between dislocations is determined by the difference between the CDW wavelength and the lattice constant of the pristine lattice. The advantage of this model as regards explaining the nonlocal voltage relies on the correlation length of the dislocation lattice. Hence, the question now moves to how far can the correlation be extended.

Coulomb repulsion plays a major role in the interaction between the dislocations since each dislocation is accompanied by an electric charge. In some CDW materials, such as NbSe_3 , uncondensed electrons remain at the Fermi surface, leading to the screening of the Coulomb potential. In the case of $o\text{-TaS}_3$, the entire Fermi surface contributes to the CDW and at low temperatures, the density of thermally activated quasiparticles is very low, so that the screening of the Coulomb potential becomes negligible. This helps to increase the correlation length of the dislocation lattice. We believe this is the most plausible model for explaining the observed nonlocal voltage.

Consequently, the observed nonlocal voltage may have three difference origins, as expressed by

$$V_{\text{nonlocal}} = V_{\text{spread}} + V_{\text{dislocation}} + V_{\text{sliding}}, \quad (2)$$

where V_{spread} , $V_{\text{dislocation}}$, and V_{sliding} denote spreading resistance, the correlated motion of the dislocation lattice, and CDW sliding, respectively. Under our experimental conditions, each term contributes as follows: $V_{\text{spread}} > 0$ for all temperatures, $V_{\text{dislocation}} < 0$ and $|V_{\text{spread}}| < |V_{\text{dislocation}}|$ below the Peierls temperature, and $V_{\text{sliding}} > 0$ above the CDW sliding threshold. Each term is schematically illustrated in Figs. 4(b)–4(d). By using these terms, Eq. (2) provides qualitative explanations for the observed peculiar behavior as shown in Figs. 3 and 4. It should be noted that the polarity of V_{sliding} is positive, thus coinciding with V_{spread} . This might be caused by the backflow of quasiparticle current accompanied by CDW sliding.¹⁹

Finally, we discuss the possible relationship between our observation and the soliton transport in a commensurate CDW.⁴ Previous studies have suggested that the low-temperature transport of $o\text{-TaS}_3$ should be understood as a CDW soliton.^{20,21} Experimentally, the anisotropy of conductivity was found to be increased at low temperatures along the chain direction.²⁰ Although the excitation energy was estimated to be 250 K, the previous results failed to detect any traces of the soliton at temperatures at which they should be excited. Assume that our observation of nonlocal voltage is

an emergence of soliton transport. The phase diagram of o -TaS₃ (Ref. 16) shows that there is commensurate CDW at 130 K. Hence, if the lifetime of the excited soliton is long enough to travel over the 200 μm , it can be a candidate to the origin of the nonlocal voltage. Since we lack unambiguous evidence for the relationship to the CDW soliton within our study, we will pursue the nature of this nonlocal voltage in further studies, including the use of optical,¹⁷ acoustic,²² and diffraction^{12,16} methods.

To summarize, we studied the nonlocal transport of a quasi-one-dimensional conductor o -TaS₃. We found that nonlocal voltages appeared in the CDW of o -TaS₃, both below and above the threshold field of CDW sliding. The tem-

perature evolution of the nonlocal voltage suggests that the observed nonlocal voltage originates from the CDW. Moreover, our observation of nonlocal voltage in both the pinned and sliding states reveals the existence of a carrier with long-range correlation, in addition to a sliding CDW and thermally excited quasiparticles.

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- ¹J. C. Gill, *Solid State Commun.* **44**, 1041 (1982).
²S. Ramakrishna, M. P. Maher, V. Ambegaokar, and U. Eckern, *Phys. Rev. Lett.* **68**, 2066 (1992).
³S. G. Lemay, R. E. Thorne, M. C. Saint-Lager, and P. Monceau, *Phys. Rev. B* **54**, 16341 (1996).
⁴G. Grüner, *Density Waves in Solids* (Addison-Wesley, Reading, MA, 1994).
⁵G. Mihály, G. Hutiray, and L. Mihály, *Phys. Rev. B* **28**, 4896 (1983).
⁶R. E. Thorne, J. H. Miller, Jr., W. G. Lyons, J. W. Lyding, and J. R. Tucker, *Phys. Rev. Lett.* **55**, 1006 (1985).
⁷J. W. Lyding, J. S. Hubacek, G. Gammie, and R. E. Thorne, *Phys. Rev. B* **33**, 4341 (1986).
⁸D. V. Borodin, S. V. Zaitsev-Zotov, and F. Ya Nad', *Sov. Phys. JETP* **66**, 793 (1987).
⁹E. Sweetland, C.-Y. Tsai, B. A. Wintner, J. D. Brock, and R. E. Thorne, *Phys. Rev. Lett.* **65**, 3165 (1990).
¹⁰J. McCarten, D. A. DiCarlo, M. P. Maher, T. L. Adelman, and R. E. Thorne, *Phys. Rev. B* **46**, 4456 (1992).
¹¹R. Danneau, A. Ayari, D. Rideau, H. Requardt, J. E. Lorenzo, L. Ortega, P. Monceau, R. Currat, and G. Grübel, *Phys. Rev. Lett.* **89**, 106404 (2002).
¹²D. Le Bolloc'h, V. L. R. Jacques, N. Kirova, J. Dumas, S. Ravy, J. Marcus, and F. Livet, *Phys. Rev. Lett.* **100**, 096403 (2008).
¹³M. Tsubota, K. Inagaki, and S. Tanda, *Physica B* **404**, 416 (2009); arXiv:0906.5206 (unpublished).
¹⁴D. V. Borodin, S. V. Zaitsev-Zotov, and F. Ya Nad', *Sov. Phys. JETP* **63**, 184 (1986).
¹⁵E. Slot, H. S. J. van der Zant, and R. E. Thorne, *Phys. Rev. B* **65**, 033403 (2001).
¹⁶K. Inagaki, M. Tsubota, K. Ichimura, S. Tanda, K. Yamamoto, N. Hanasaki, Y. Nogami, N. Ikeda, T. Ito, and H. Toyokawa, *J. Phys. Soc. Jpn.* **77**, 093708 (2008).
¹⁷Y. Toda, R. Onozaki, M. Tsubota, K. Inagaki, and S. Tanda, *Phys. Rev. B* **80**, 121103(R) (2009).
¹⁸W. L. McMillan, *Phys. Rev. B* **14**, 1496 (1976).
¹⁹H. S. J. van der Zant, E. Slot, S. V. Zaitsev-Zotov, and S. N. Artemenko, *Phys. Rev. Lett.* **87**, 126401 (2001).
²⁰T. Takoshima, M. Ido, K. Tsutsumi, T. Sambongi, S. Honma, K. Yamaya, and Y. Abe, *Solid State Commun.* **35**, 911 (1980).
²¹K. Maki, *Phys. Rev. Lett.* **39**, 46 (1977).
²²B. A. Malomed, *J. Phys. Soc. Jpn.* **62**, 997 (1993).